

Superconducting microwave resonators for spin-photon coupling in silicon

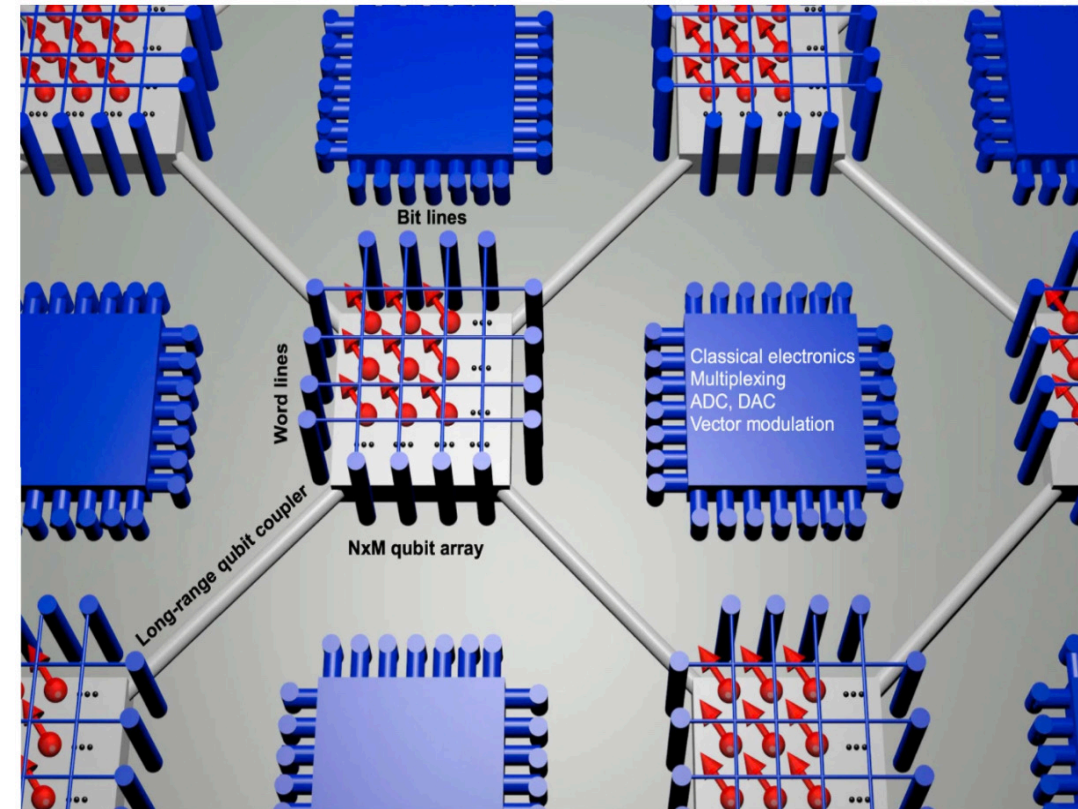
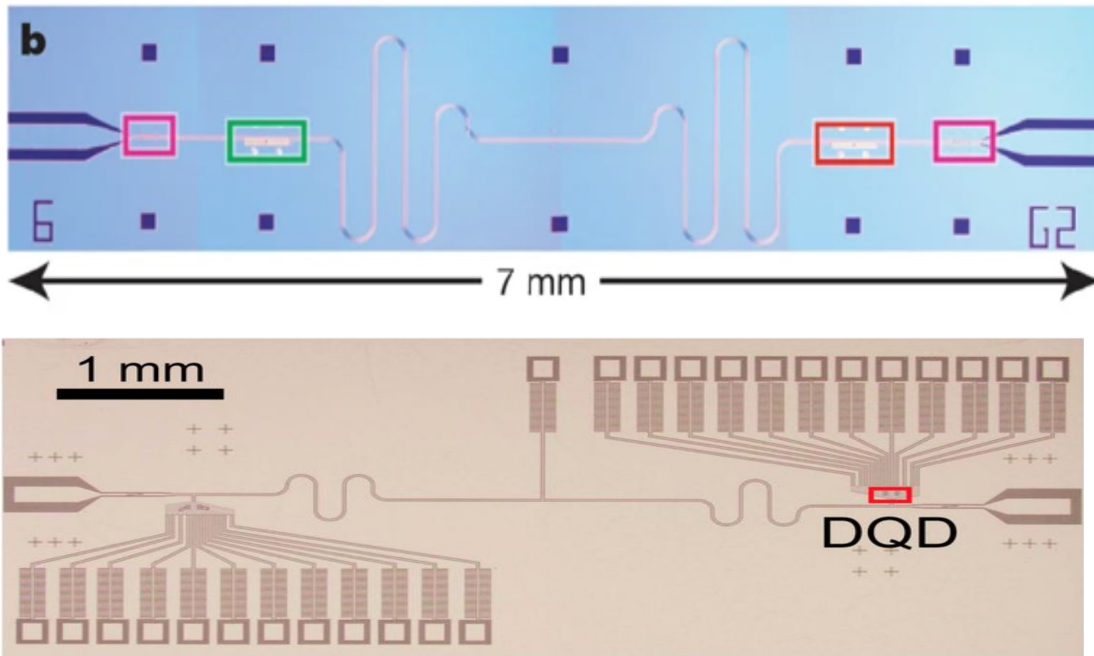
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Superconducting microwave resonators

- Superconducting wires in various shapes
- Long distance qubit coupling [1]
- Scale up of Quantum computing architecture [2]



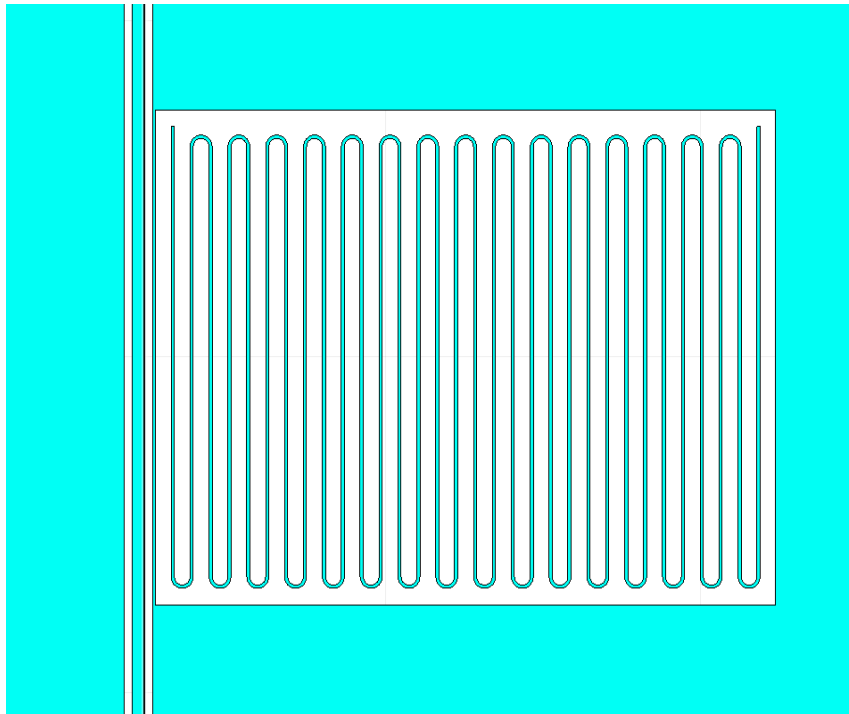
1. Majer, J., Chow, J., Gambetta, J. *et al.* Coupling superconducting qubits via a cavity bus. *Nature* **449**, 443–447 (2007).
2. Mi, X. and Cady, J. V. and Zajac, D. M. and Deelman, P. W. and Petta, J. R. - *Science* (2017)
3. Vandersypen, L.M.K., Bluhm, H., Clarke, J.S. *et al.* Interfacing spin qubits in quantum dots and donors—hot, dense, and coherent. *npj Quantum Inf* **3**, 34 (2017).

Boron In silicon

- Intrinsic spin orbit coupling
- Past results show comparable coherence times with other spin systems in Silicon [1].
- Easy integration into established Silicon foundry.
- Electric drive of Boron in Silicon using Superconducting Microwave resonators.
- Strong Electric field in resonators means stronger coupling to dopants.
- Resonators facilitate driving and readout of dopant qubits.

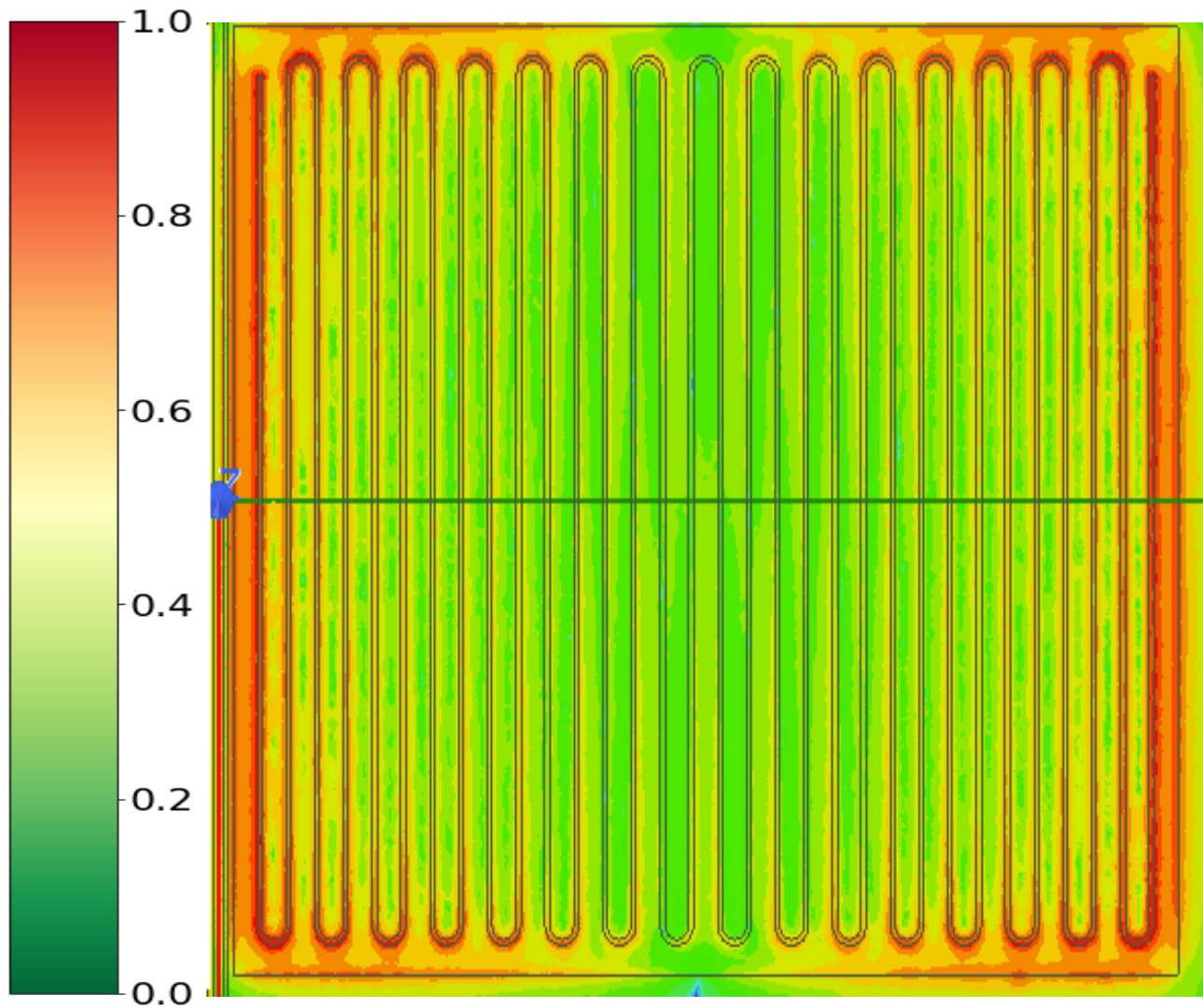
Required properties of superconducting resonators

- Resonance Tunability for ESR applications [1]
- Magnetic Field resilient[2]
- High Electric field in small mode volumes

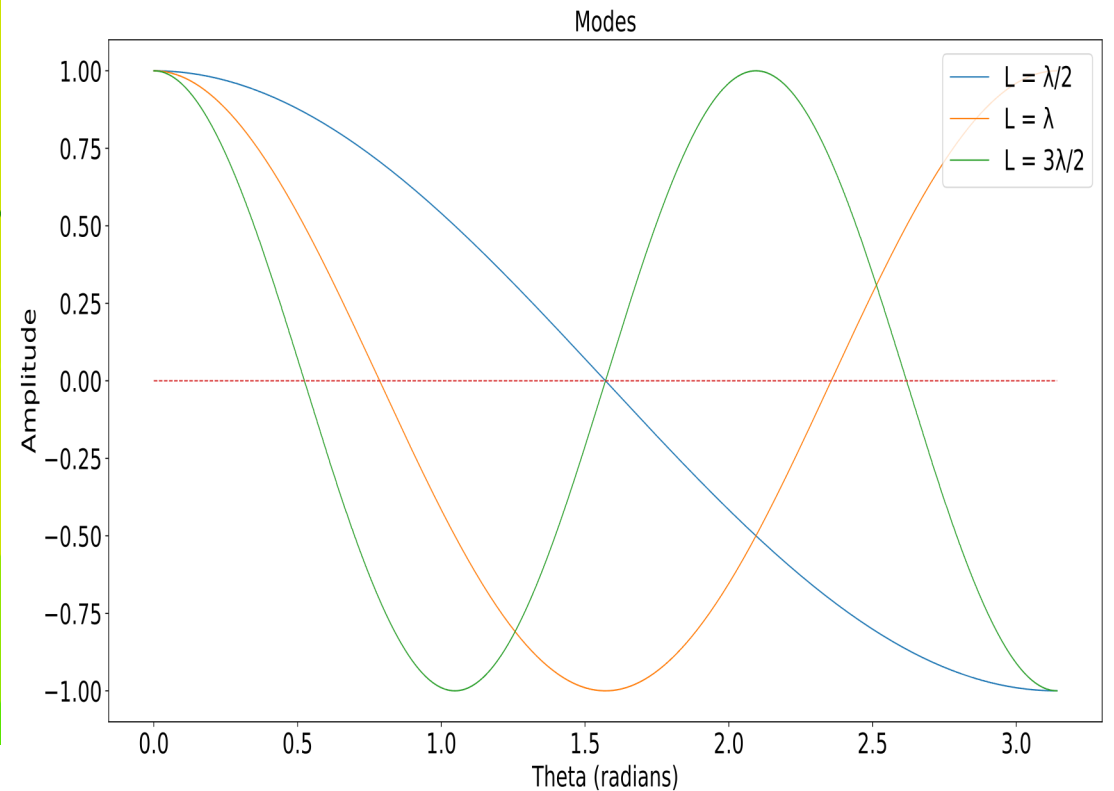


1. Sumedh Mahashabde, Ernst Otto, Domenico Montemurro, Sebastian de Graaf, Sergey Kubatkin, and Andrey Danilov Phys. Rev. Applied **14**, 044040
2. Cécile Xinqing Yu, Simon Zihlmann, Gonzalo Troncoso Fernández-Bada, Jean-Luc Thomassin, Frédéric Gustavo, Étienne Dumur, and Romain Maurand , "Magnetic field resilient high kinetic inductance superconducting niobium nitride coplanar waveguide resonators", Appl. Phys. Lett. 118, 054001 (2021)

Superconducting microwave resonators



$$f_{resonance} = \frac{1}{\sqrt{L_l C_l}} \frac{1}{2l}$$



Superconducting resonator

$$f_{resonance} = \frac{1}{\sqrt{L_l C_l}} \frac{1}{l}$$

$$L_l = L_{Geometric} + L_{kinetic}$$

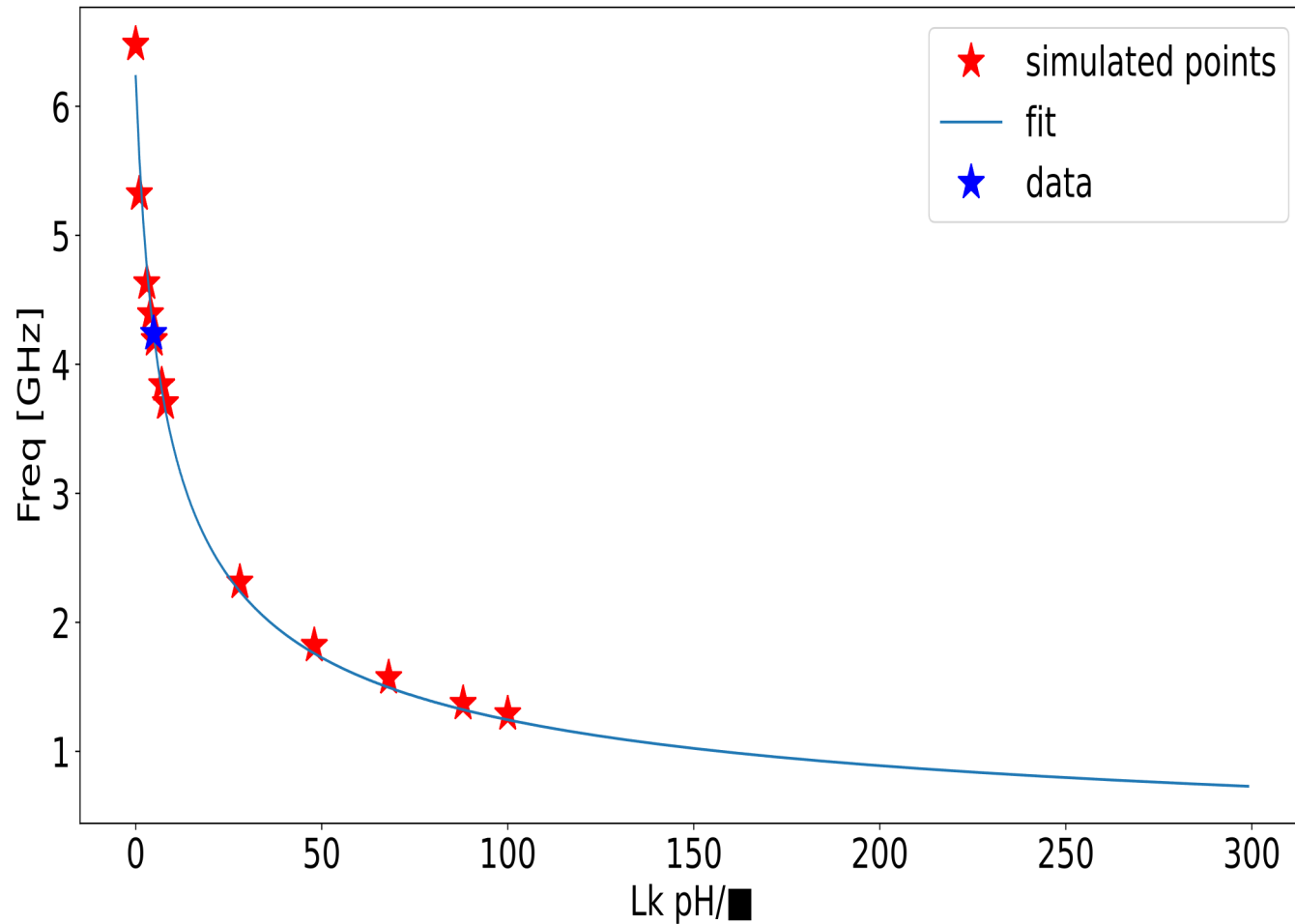
$$L_{kin} = \frac{\hbar R_{\blacksquare}}{\pi \Delta_0}$$

$\Delta_0 =$ superconducting energy gap $\propto T_c$

$$Z_o = \sqrt{\frac{L_l}{C_l}}$$
$$V_{rms} \propto \sqrt{Z_o}$$

- $L_{kinetic}$ a property of a superconductor
- Can move resonant frequency of resonator
- Can affect the electric field in the mode volume of resonator

Lk vs film thickness simulation / experimental



$$y = \frac{1}{\sqrt{ax + b}}$$

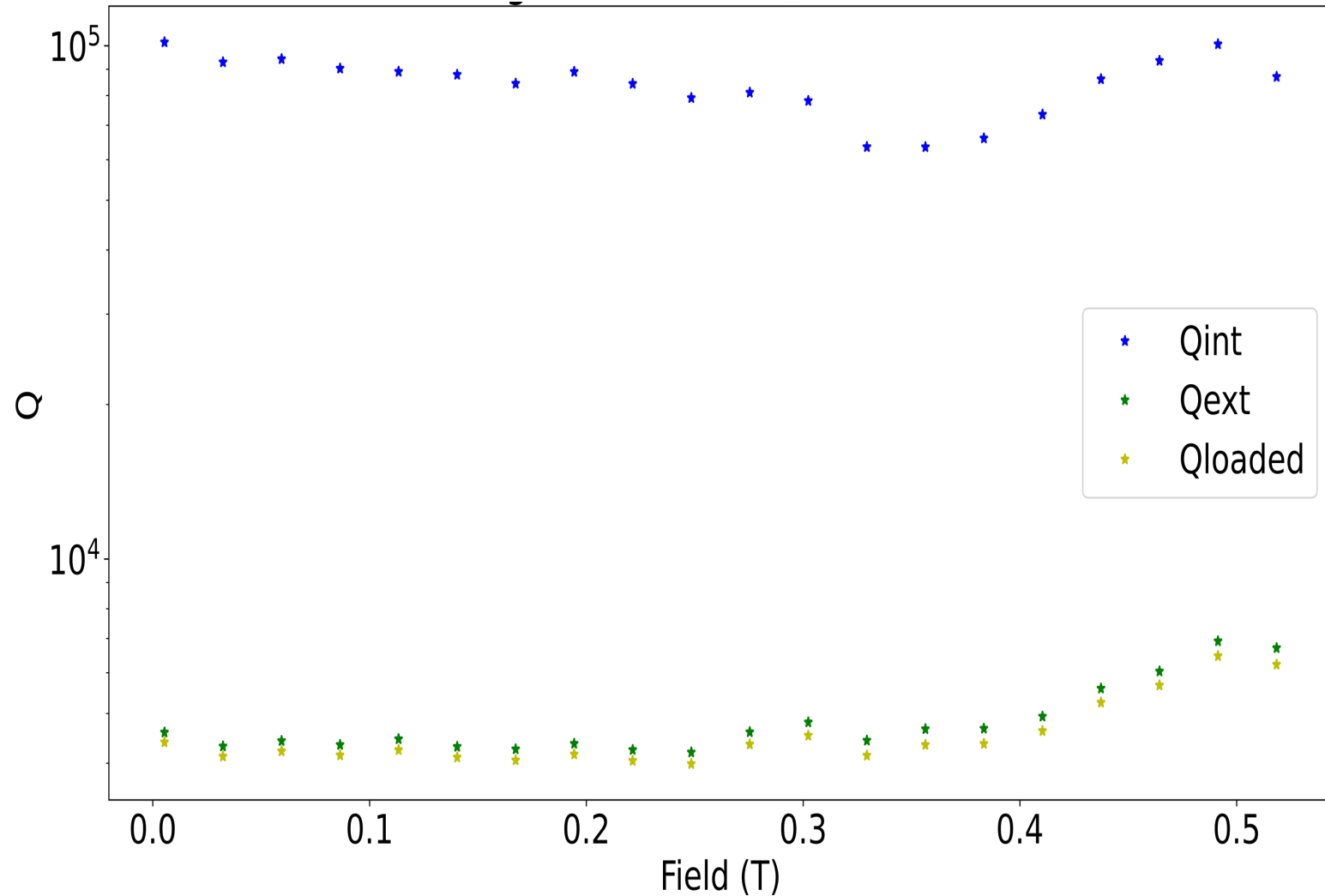
- 50nm NbTiN film
- Freq= 4.2376 GHz
- Lk = 4.83 pH/square

Name	Thickness [nm]	Sheet Kinetic inductance [pH/square]
NbTiN	8-12	13
WSi	16-20	33.5

Superconducting resonator

- Internal Q
- External Q
- Loaded Q

$$\frac{1}{Q_L} = \frac{1}{Q_{internal}} + \frac{1}{Q_{external}}$$

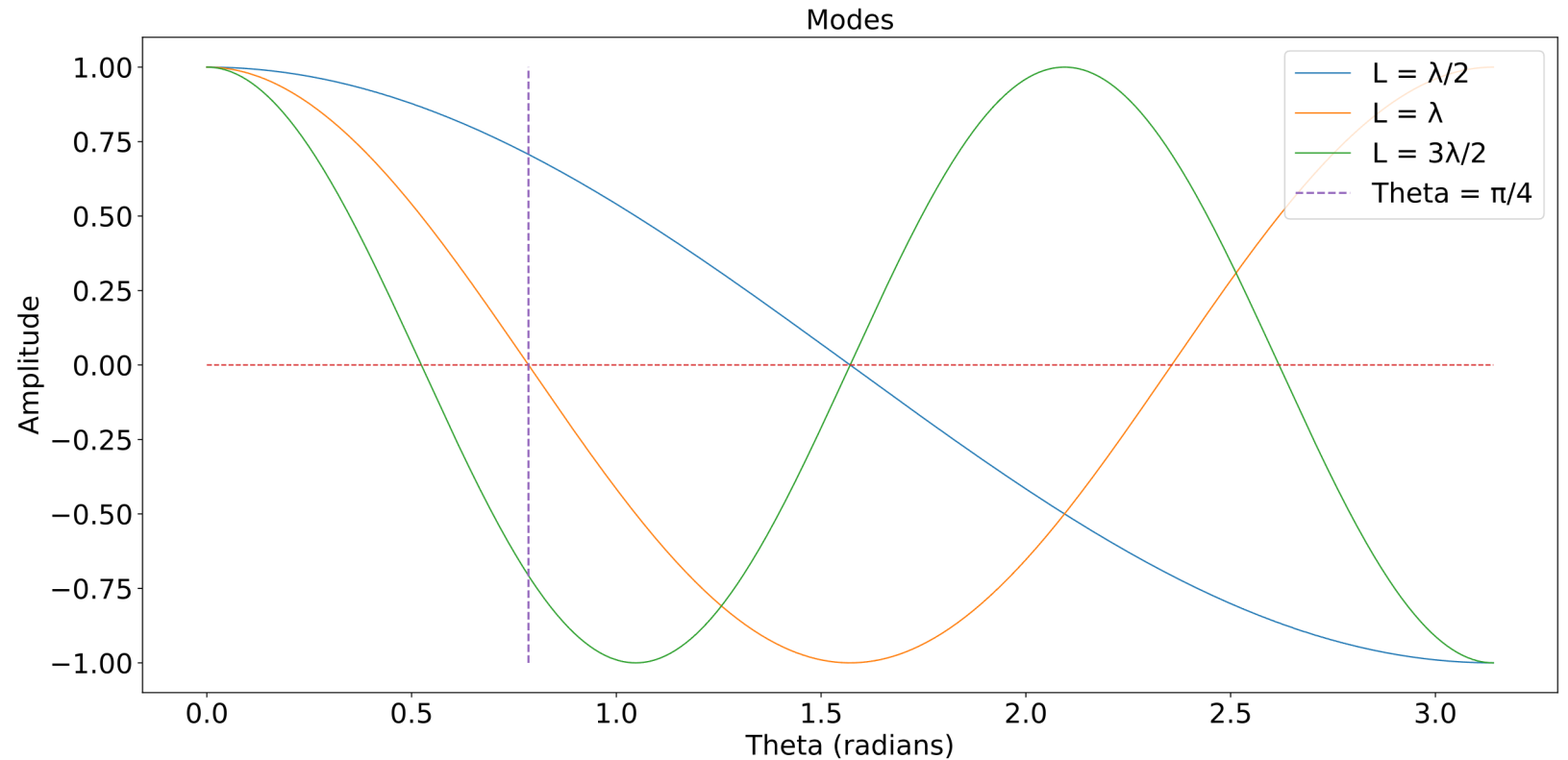
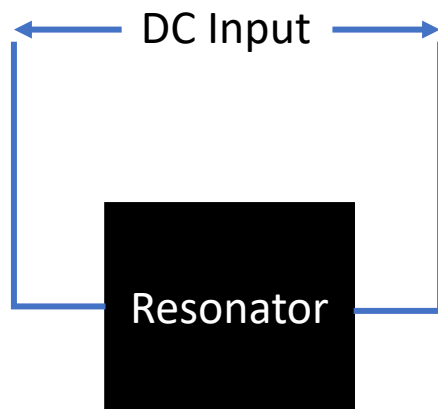


Conclusion

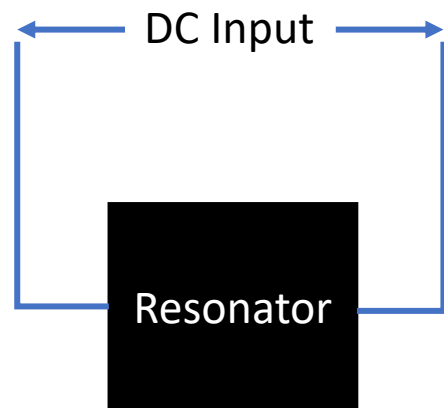
- The resonators were found to be B resilient, which is important for ESR experiments.
- High internal Qs resilient to magnetic fields
- High Lk guarantees better E field localization.

Outlook

- Resonance tuning
- Electric drive of Dopant systems with spin orbit coupling



Towards Tunable resonators



$$L_k = L_k(0) \left(1 + \left(\frac{I}{I_*} \right)^2 \right) [1]$$

